

Vishay Siliconix

Automotive P-Channel 30 V (D-S) 175 °C MOSFET



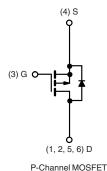
PRODUCT SUMMARY					
V _{DS} (V)	- 30				
$R_{DS(on)}(\Omega)$ at $V_{GS} = -10 \text{ V}$	0.043				
$R_{DS(on)}(\Omega)$ at $V_{GS} = -4.5 \text{ V}$	0.070				
I _D (A)	- 7.5				
Configuration	Single				

FEATURES

- TrenchFET® Power MOSFET
- AEC-Q101 Qualified^c
- 100 % R_q and UIS Tested
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>







ORDERING INFORMATION	
Package	TSOP-6
Lead (Pb)-free and halogen-free	SQ3481EV (for detailed order number please see www.vishay.com/doc?79771)

ABSOLUTE MAXIMUM RATINGS (T _C = 25 °C, unless otherwise noted)						
PARAMETER	SYMBOL	LIMIT	UNIT			
Drain-Source Voltage	V_{DS}	- 30	V			
Gate-Source Voltage	V_{GS}	± 20	V			
Continuous Drain Current	T _C = 25 °C	1	- 7.5			
	T _C = 125 °C	l _D	- 4.3			
Continuous Source Current	I _S	- 5.2	Α			
Pulsed Drain Current ^a	I _{DM}	- 30				
Single Pulse Avalanche Current	L = 0.1 mH	I _{AS}	- 15			
Single Pulse Avalanche Energy	L = U.1 MIH	E _{AS}	11	mJ		
Maximum Power Dissipation ^a	T _C = 25 °C	P _D	4	W		
	T _C = 125 °C		1.3	VV		
Operating Junction and Storage Temperatu	re Range	T _J , T _{stg}	- 55 to + 175	°C		

THERMAL RESISTANCE RATINGS				
PARAMETER		SYMBOL	LIMIT	UNIT
Junction-to-Ambient F	PCB Mount ^b	R _{thJA}	110	°C/W
Junction-to-Foot (Drain)		R_{thJF}	36	G/VV

Notes

- a. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2 %
- b. When mounted on 1" square PCB (FR-4 material)
- c. Parametric verification ongoing



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SPECIFICATIONS (T _C = 25 °C, unless otherwise noted)								
PARAMETER	SYMBOL	TES	MIN.	TYP.	MAX.	UNIT		
Static					•			
Drain-Source Breakdown Voltage	V _{DS}	V _{GS} =	$V_{GS} = 0 \text{ V}, I_D = -250 \mu\text{A}$		-	-	V	
Gate-Source Threshold Voltage	V _{GS(th)}	V _{DS} =	V _{GS} , I _D = - 250 μA	- 1.5	- 2.0	- 2.5	V	
Gate-Source Leakage	I _{GSS}	V _{DS} =	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$		-	± 100	nA	
		V _{GS} = 0 V	V _{DS} = - 30 V	-	-	- 1		
Zero Gate Voltage Drain Current	I _{DSS}	V _{GS} = 0 V	V _{DS} = - 30 V, T _J = 125 °C	-	-	- 50	μΑ	
		V _{GS} = 0 V	V _{DS} = - 30 V, T _J = 175 °C	-	-	- 150	1	
On-State Drain Current ^a	I _{D(on)}	V _{GS} = - 10 V	V _{DS} ≤ - 5 V	- 10	-	-	Α	
Dunin Course On Chata Basistanas	R _{DS(on)}	V _{GS} = - 10 V	I _D = - 5.3 A	-	0.035	0.043		
Drain-Source On-State Resistance ^a		V _{GS} = - 4.5 V	I _D = - 2 A	-	0.055	0.070	Ω	
Forward Transconductance ^b	9 _{fs}	V _{DS} =	- 15 V, I _D = - 5.3 A	-	13	-	S	
Dynamic ^b								
Input Capacitance	C _{iss}			-	695	870		
Output Capacitance	C _{oss}	$V_{GS} = 0 V$	V _{DS} = - 15 V, f = 1 MHz	-	160	200	pF	
Reverse Transfer Capacitance	C _{rss}	1		-	120	150		
Total Gate Charge ^c	Q _g			-	15.4	23.5		
Gate-Source Charge ^c	Q _{gs}	V _{GS} = - 10 V	$V_{DS} = -15 \text{ V}, I_{D} = -5.3 \text{ A}$	-	2.1		nC	
Gate-Drain Charge ^c	Q_{gd}	1		-	3.9			
Gate Resistance	R_g		f = 1 MHz		11.5	18.5	Ω	
Turn-On Delay Time ^c	t _{d(on)}			-	9	14		
Rise Time ^c	t _r	V_{DD} = - 15 V, R_L = 15 Ω I_D \cong - 1 A, V_{GEN} = - 10 V, R_g = 1 Ω		-	15	23	- ns	
Turn-Off Delay Time ^c	t _{d(off)}			-	28	42		
Fall Time ^c	t _f			-	12	18		
Pulsed Current ^a	I _{SM}			ı	-	- 30	Α	
Forward Voltage	V _{SD}	I _F = - 1.7 A, V _{GS} = 0 V		-	- 0.8	- 1.2	V	

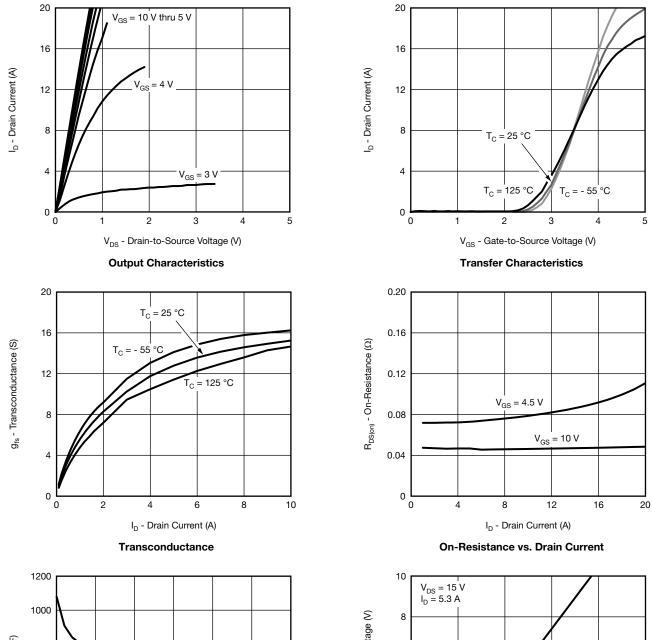
Notes

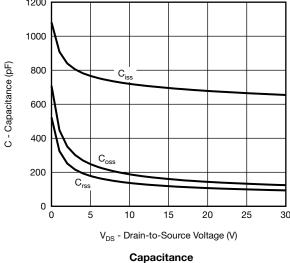
- a. Pulse test; pulse width $\leq 300~\mu s,~duty~cycle \leq 2~\%$
- b. Guaranteed by design, not subject to production testing
- c. Independent of operating temperature

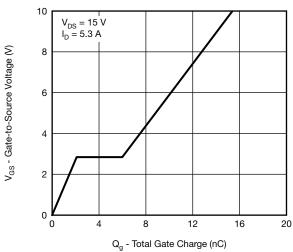
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



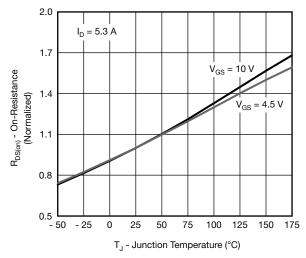




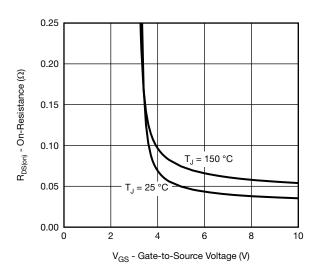
Gate Charge



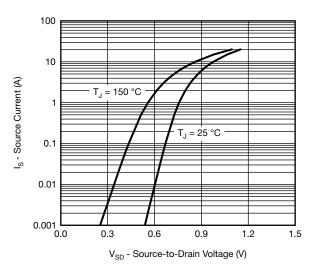
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



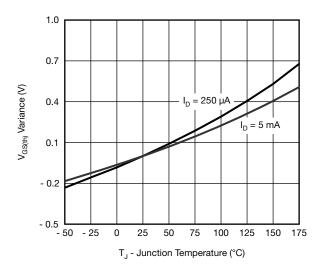
On-Resistance vs. Junction Temperature



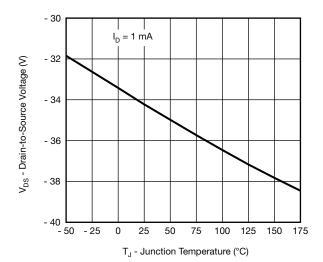
On-Resistance vs. Gate-to-Source Voltage



Source-Drain Diode Forward Voltage



Threshold Voltage

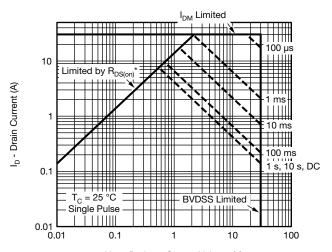


Drain Source Breakdown vs. Junction Temperature

For technical questions, contact: automostech

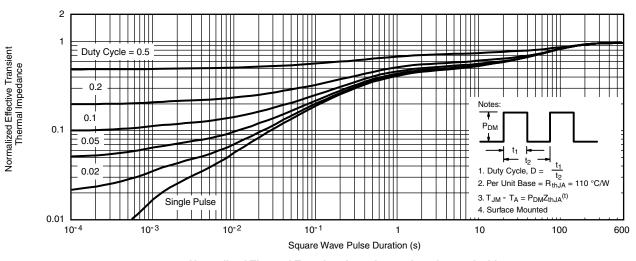


THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



 $\rm V_{DS}$ - Drain-to-Source Voltage (V) * $\rm V_{GS}$ > minimum $\rm V_{GS}$ at which $\rm R_{DS(on)}$ is specified

Safe Operating Area

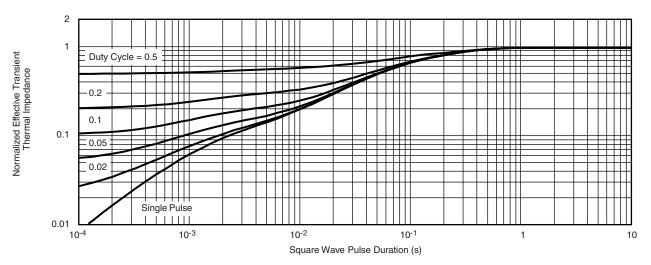


Normalized Thermal Transient Impedance, Junction-to-Ambient

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THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Foot

Note

- The characteristics shown in the two graphs
- Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)
- Normalized Transient Thermal Impedance Junction-to-Foot (25 °C)

are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

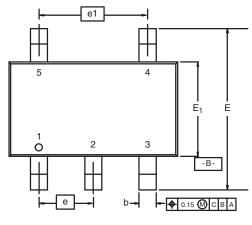
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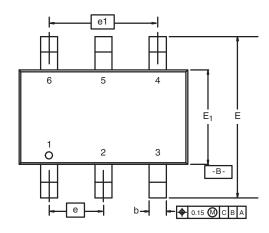




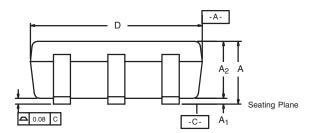
TSOP: 5/6-LEAD

JEDEC Part Number: MO-193C

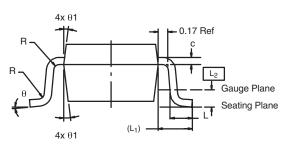




5-LEAD TSOP







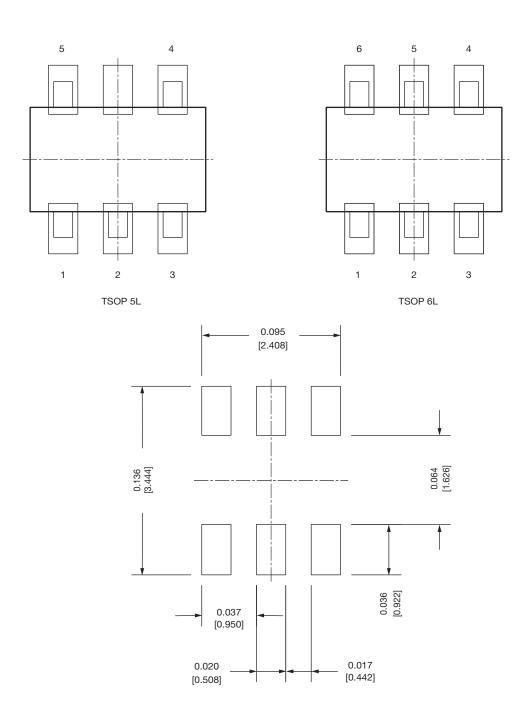
	MIL	LIMETER	RS	INCHES			
Dim	Min	Nom	Max	Min	Nom	Max	
Α	0.91	-	1.10	0.036	-	0.043	
A ₁	0.01	-	0.10	0.0004	-	0.004	
A ₂	0.90	-	1.00	0.035	0.038	0.039	
b	0.30	0.32	0.45	0.012	0.013	0.018	
С	0.10	0.15	0.20	0.004	0.006	0.008	
D	2.95	3.05	3.10	0.116	0.120	0.122	
E	2.70	2.85	2.98	0.106	0.112	0.117	
E ₁	1.55	1.65	1.70	0.061	0.065	0.067	
е		0.95 BSC		0.0374 BSC			
e ₁	1.80	1.90	2.00	0.071	0.075	0.079	
L	0.32	-	0.50	0.012	-	0.020	
L ₁		0.60 Ref		0.024 Ref			
L ₂		0.25 BSC			0.010 BSC		
R	0.10	-	-	0.004	-	-	
θ	0°	4°	8°	0°	4°	8°	
θ1		7° Nom 7° Nom					
ECN: C-06593-Rev. I, 18-Dec-06 DWG: 5540							

DWG: 5540

Document Number: 71200 18-Dec-06



Recommended Land Pattern For TSOP-5L / TSOP-6L



Note

• All dimensions are in inches (millimeter)

ECN: C22-0860-Rev. B, 24-Oct-2022 DWG: 3010



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